www.DataSheet4U-f@SHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

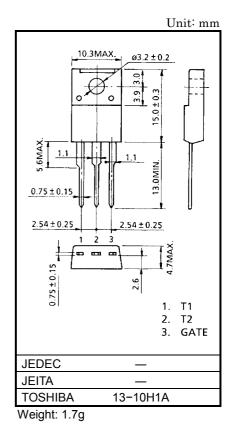
SM3GZ47,SM3JZ47

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : VDRM = 400, 600V
- R.M.S ON–State Current
- : I_T (RMS) = 3A
- High Commutating (dv / dt)
- Isolation Voltage
- : VISOL = 1500V AC

MAXIMUM RATINGS

CHARACTERIS	SYMBOL	RATING	UNIT		
Repetitive Peak Off-State Voltage	SM3GZ47	VDRM	400	V	
	SM3JZ47	VDRM	600		
R.M.S On-State Current (Full Sine Waveform Tc =	I _{T (RMS)}	3	А		
Peak One Cycle Surge On-State Current (Non-Repetitive)		Irou	30 (50Hz)	А	
		ITSM	33 (60Hz)	~	
I ² t Limit Value (t = 1~10n	l ² t	4.5	A ² s		
Critical Rate of Rise of O Current	di / dt	50	A / µs		
Peak Gate Power Dissip	P _{GM}	5	W		
Average Gate Power Dis	P _{G (AV)}	0.5	W		
Peak Gate Voltage	V _{GM}	10	V		
Peak Gate Current	I _{GM}	2	А		
Junction Temperature	Tj	-40~125	°C		
Storage Temperature Ra	T _{stg}	-40~125	°C		
Isolation Voltage (AC, t =	VISOL	1500	V		



Note 1: di / dt test condition $V_{DRM} = 0.5 \times Rated$ $I_{TM} \le 4.5A$ $t_{gw} \ge 10 \mu s$ $t_{gr} \le 250 ns$ $i_{gp} = I_{GT} \times 2.0$

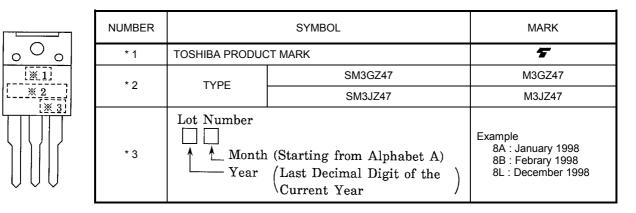
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www.DataShaet411, com ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated		_	_	20	μA
Gate Trigger Voltage	Ι	- V _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	—	_	1.5	- V
	II			T2 (+), Gate (-)	_	_	1.5	
	III			T2 (-), Gate (-)	—	_	1.5	
	IV			T2 (-), Gate (+)	_	_	_	
Gate Trigger Current	I	IGT	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	20	- mA
	II			T2 (+), Gate (-)	_	_	20	
	III			T2 (-), Gate (-)	_	_	20	
	IV			T2 (-), Gate (+)	_	_	_	
Peak On-State Voltage		V _{TM}	I _{TM} = 4.5A		_	_	1.5	V
Gate Non-Trigger Voltage		V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		Ι _Η	V _D = 12V, I _{TM} = 1A		_	_	30	mA
Thermal Resistance		R _{th (j−c)}	Junction to Case, AC		_	_	4.2	°C/W
Critical Rate of Rise of Off-State Voltage		dv / dt	V _{DRM} = Rated, T _j = 125°C Exponential Rise		_	300	_	V / µs
Critical Rate of Rise of Off-State Voltage at Commutation		(dv / dt) c	V _{DRM} = 400V, T _j = 125°C (di /dt) c = -2.0A / ms		10	_	_	V / µs

MARKING



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0.6

0.2

-40

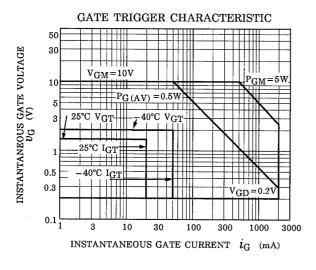
0

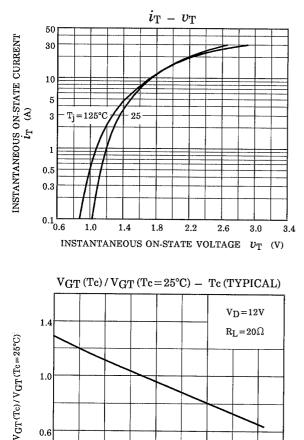
40

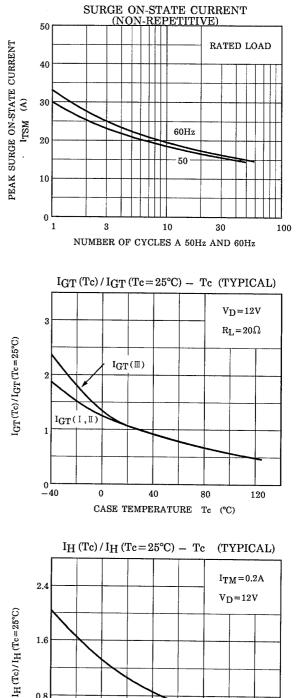
CASE TEMPERATURE Tc (°C)

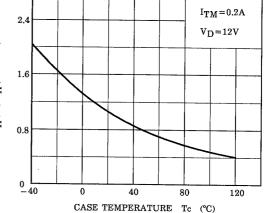
80

120



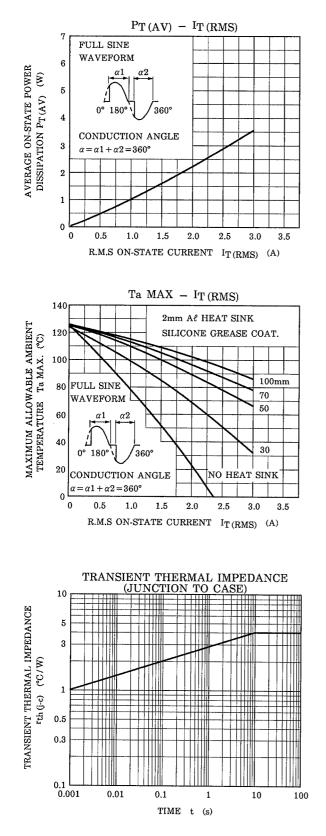


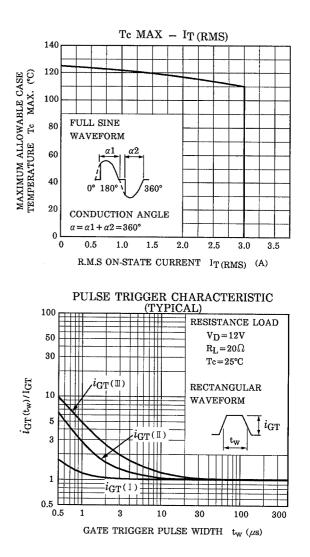




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